

## Vishay Semiconductors

## Silicon Photodiode, RoHS Compliant



#### **DESCRIPTION**

BPW20RF is a planar Silicon PN photodiode in a hermetically sealed short TO-5 case, especially designed for high precision linear applications.

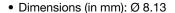
Due to its extremely high dark resistance, the short circuit photocurrent is linear over seven decades of illumination level.

On the other hand, there is a strictly logarithmic correlation between open circuit voltage and illumination over the same range.

Equipped with a clear, flat glass window, the spectral responsitivity reaches from blue to near infrared.

#### **FEATURES**

Package type: leadedPackage form: TO-5



• Radiant sensitive area (in mm<sup>2</sup>): 7.5

High photo sensitivity

· High radiant sensitivity

- · Suitable for visible and near infrared radiation
- Angle of half sensitivity:  $\varphi = \pm 50^{\circ}$
- · Hermetically sealed package
- · Cathode connected to package
- · Flat glass window
- UV enhanced
- · Low dark current
- · High shunt resistance
- · High linearity
- Compliant to RoHS Directive 2002/95/EC and in accordance with WEEE 2002/96/EC

#### **APPLICATIONS**

 Sensor for light measuring techniques in cameras, photometers, color analyzers, exposure meters (e.g. solariums) and other medical and industrial measuring and control applications.

PRODUCT SUMMARY			
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.1</sub> (nm)
BPW20RF	60	± 50	400 to 1100

#### Note

· Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW20RF	Bulk	MOQ: 500 pcs, 500 pcs/bulk	TO-5	

#### Noto

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	10	V	
Power dissipation	T <sub>amb</sub> ≤ 50 °C	P <sub>V</sub>	300	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 125	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 125	°C	
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	250	K/W	



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<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	$V_{F}$		1.0	1.3	V
Breakdown voltage	$I_R = 20 \mu A, E = 0$	V <sub>(BR)</sub>	10			V
Reverse dark current	V <sub>R</sub> = 5 V, E = 0	I <sub>ro</sub>		2	30	nA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	$C_D$		1.2		nF
	V <sub>R</sub> = 5 V, f = 1 MHz, E = 0	$C_D$		400		pF
Dark resistance	V <sub>R</sub> = 10 mV	$R_D$		38		GΩ
Open circuit voltage	E <sub>A</sub> = 1 klx	Vo	330	500		mV
Temperature coefficient of Vo	E <sub>A</sub> = 1 klx	$TK_Vo$		- 2		mV/K
Short circuit current	E <sub>A</sub> = 1 klx	l <sub>k</sub>	20	60		μΑ
Temperature coefficient of I <sub>k</sub>	E <sub>A</sub> = 1 klx	TK <sub>lk</sub>		0.1		%/K
Reverse light current	E <sub>A</sub> = 1 klx, V <sub>R</sub> = 5 V	I <sub>ra</sub>	20	60		μΑ
	$E_e$ = 1 mW/cm <sup>2</sup> , $\lambda$ = 950 nm, $V_R$ = 5 V	I <sub>ra</sub>		42		μΑ
Angle of half sensitivity		φ		± 50		deg
Wavelength of peak sensitivity		$\lambda_{p}$		920		nm
Range of spectral bandwidth		λ <sub>0.1</sub>	400		1100	nm
Rise time	$V_R = 0 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>r</sub>		3.4		μs
Fall time	$V_R = 0 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t <sub>f</sub>		3.7		μs

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

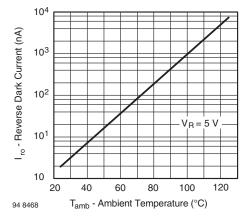


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

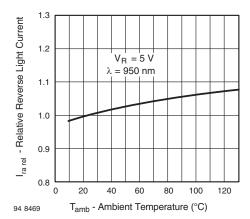


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

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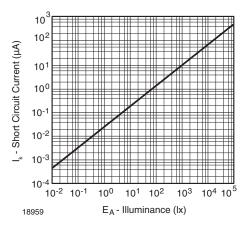


Fig. 3 - Short Circuit Current vs. Illuminance

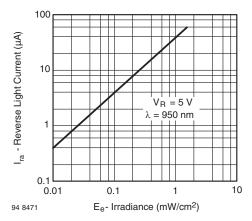


Fig. 4 - Reverse Light Current vs. Irradiance

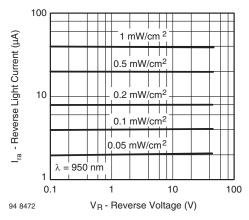


Fig. 5 - Reverse Light Current vs. Reverse Voltage

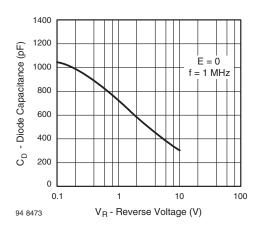


Fig. 6 - Diode Capacitance vs. Reverse Voltage

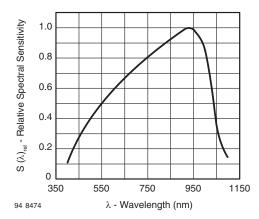


Fig. 7 - Relative Spectral Sensitivity vs. Wavelength

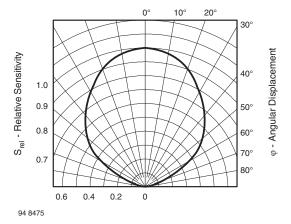
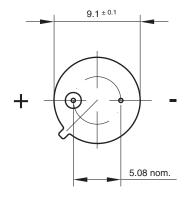
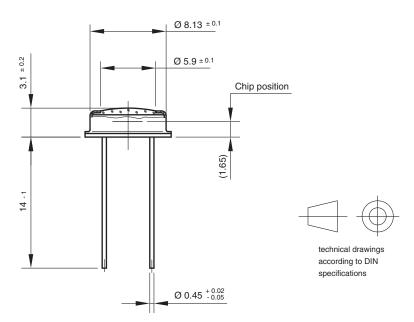


Fig. 8 - Relative Radiant Sensitivity vs. Angular Displacement

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#### **PACKAGE DIMENSIONS** in millimeters





Drawing-No.: 6.511-5002.01-4

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